Material Composition Specification







Device average mass	18.0 g
Fluctuation margin	+/-10%

Component	Material	Material		Substance	CAS No.	Substance		
		(%wt)	(mg)	Substance	CA3 NO.	(%wt)	(mg)	(ppm)
active device	doped Si	0.242%	43.58	Si	7440-21-3	0.23%	41.4	2,299
				Ni	7440-02-0	0.012%	2.18	121
leadframe	copper	24.26%	4,367	Cu	7440-50-8	24.26%	4,367	242,611
plating	nickel	0.03%	5.4	Ni	7440-02-0	0.03%	5.4	300
die attach	high temperature solder 13.245	13.245%	245% 2,384	Pb	7439-92-1	0.005%	0.945	53
				Sn	7440-31-5	0.0001%	0.05	3
				Cu	7440-50-8	13.24%	2,383	132,392
encapsulation	EMC with aluminum heatsink 62.2	62.220/	11,200	epoxy resin	Proprietary	53.57%	9,640	535,556
		02.23%		AI	7429-90-5	8.67%	1,560	86,667

*EMC GREEN molding compound is Halogen-Free.

Disclaimer

The information provided in this Material Composition data sheet is, to the best of our knowledge, correct. However, there is no guarantee to completeness or accuracy, as some information is derived from data sources outside the company.

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